



INFORMATION DISCLOSURE CITATION
(Use several sheets if necessary)

ATTY DOCKET NO. ITL.1056US (P17793)	SERIAL NO. 10/764,193
APPLICANT(S): MICHAEL MCSWINEY, ET AL.	
FILING DATE: January 23, 2004	GROUP ART UNIT:

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
A.						
B.						
C.						
D.						
E.						
F.						
G.						
H.						
I.						

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
						YES
J.						
K.						
L.						
M.						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

/RB/	N.	Inventors: Michael L. McSwiney and Michael D. Goodner, Patent Application entitled: <i>Low-Temperature Silicon Nitride Deposition</i> , filed July 30, 2003, Serial No. 10/631,627, Patent Application has 15 pages and 4 pages of drawings
/RB/	O.	Author: SCHUMACHER, A UNIT OF AIR PRODUCTS AND CHEMICALS, INC.; entitled: <i>BTBAS Silicon Nitride</i> ; 1 page; www.schumacher.com/btbas , date unknown.
	P.	
	Q.	
	R.	
	S.	
	T.	

EXAMINER /Renee Berry/ DATE CONSIDERED 10/01/2007

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